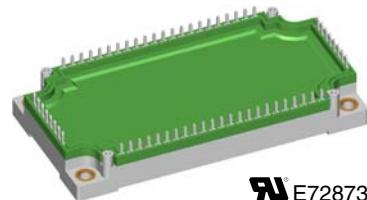
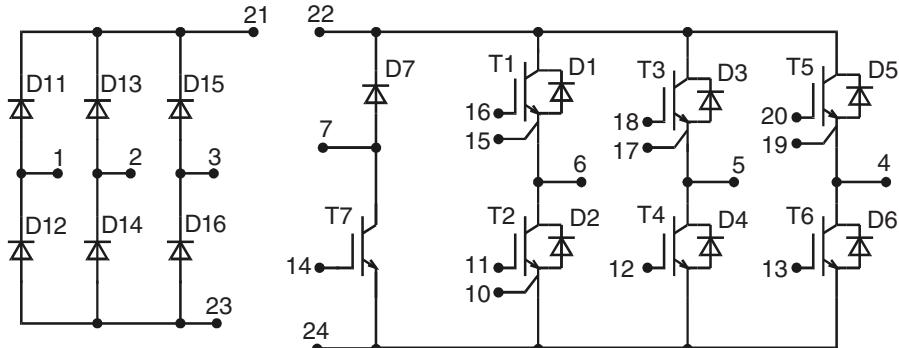
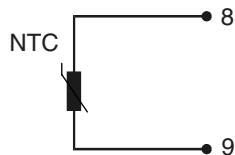


Converter - Brake - Inverter Module (CBI3)



See outline drawing for pin arrangement

Preliminary data



Three Phase Rectifier	Brake Chopper	Three Phase Inverter
$V_{RRM} = 1600 \text{ V}$	$V_{CES} = 600 \text{ V}$	$V_{CES} = 600 \text{ V}$
$I_{FAV} = 90 \text{ A}$	$I_{C25} = 50 \text{ A}$	$I_{C25} = 125 \text{ A}$
$I_{FSM} = 850 \text{ A}$	$V_{CE(sat)} = 1.9 \text{ V}$	$V_{CE(sat)} = 1.9 \text{ V}$

Input Rectifier D11 - D16

Symbol	Conditions	Maximum Ratings		
V_{RRM}		1600	V	
I_{FAV}	$T_c = 80^\circ\text{C}$; sine 180°	65	A	
I_{DAVM}	$T_c = 80^\circ\text{C}$; rectangular; $d = 1/3$; bridge	180	A	
I_{FSM}	$T_{VJ} = 25^\circ\text{C}$; $t = 10 \text{ ms}$; sine 50 Hz	850	A	
P_{tot}	$T_c = 25^\circ\text{C}$	170	W	

Symbol	Conditions	Characteristic Values		
		($T_{VJ} = 25^\circ\text{C}$, unless otherwise specified)	min.	typ.
V_F	$I_F = 100 \text{ A}$; $T_{VJ} = 25^\circ\text{C}$ $T_{VJ} = 125^\circ\text{C}$		1.3	1.5
			1.3	V
I_R	$V_R = V_{RRM}$, $T_{VJ} = 25^\circ\text{C}$ $T_{VJ} = 125^\circ\text{C}$		1	0.05 mA
				mA
R_{thJC}	(per diode)		0.73	K/W

Application: AC motor drives with

- € Input from single or three phase grid
- € Three phase synchronous or asynchronous motor
- € Electric braking operation

Features

- € High level of integration - only one power semiconductor module required for the whole drive
- € NPT IGBT technology with low saturation voltage, low switching losses, high RBSOA and short circuit ruggedness
- € Epitaxial free wheeling diodes with Hiperfast and soft reverse recovery
- € Industry standard package with insulated copper base plate and soldering pins for PCB mounting
- € Temperature sense included

Output Inverter T1 - T6

Symbol	Conditions	Maximum Ratings		
V_{CES}	$T_{VJ} = 25^\circ\text{C}$ to 150°C	600		V
V_{GES}	Continuous		± 20	V
I_{C25}	$T_C = 25^\circ\text{C}$	125		A
I_{C80}	$T_C = 80^\circ\text{C}$	85		A
RBSOA	$V_{GE} = \pm 15\text{ V}$; $R_G = 2.2\text{ }\Omega$; $T_{VJ} = 125^\circ\text{C}$ Clamped inductive load; $L = 100\text{ }\mu\text{H}$	$I_{CM} = 200$ $V_{CEK} \leq V_{CES}$		A
t_{sc} (SCSOA)	$V_{CE} = V_{CES}$; $V_{GE} = \pm 15\text{ V}$; $R_G = 2.2\text{ }\Omega$; $T_{VJ} = 125^\circ\text{C}$ non-repetitive	10		μs
P_{tot}	$T_C = 25^\circ\text{C}$	410		W

Symbol	Conditions	Characteristic Values		
		($T_{VJ} = 25^\circ\text{C}$, unless otherwise specified)	min.	typ.
$V_{CE(sat)}$	$I_C = 100\text{ A}$; $V_{GE} = 15\text{ V}$; $T_{VJ} = 25^\circ\text{C}$ $T_{VJ} = 125^\circ\text{C}$		1.9 2.2	2.5 V V
$V_{GE(th)}$	$I_C = 1.5\text{ mA}$; $V_{GE} = V_{CE}$	4.5		6.5 V
I_{CES}	$V_{CE} = V_{CES}$; $V_{GE} = 0\text{ V}$; $T_{VJ} = 25^\circ\text{C}$ $T_{VJ} = 125^\circ\text{C}$		1.5	1.4 mA mA
I_{GES}	$V_{CE} = 0\text{ V}$; $V_{GE} = \pm 20\text{ V}$		400	nA
$t_{d(on)}$ t_r $t_{d(off)}$ t_f E_{on} E_{off}	$\left. \begin{array}{l} \text{Inductive load, } T_{VJ} = 125^\circ\text{C} \\ V_{CE} = 300\text{ V}; I_C = 100\text{ A} \\ V_{GE} = \pm 15\text{ V}; R_G = 2.2\text{ }\Omega \end{array} \right\}$		25 11 150 30 1.0 2.9	ns ns ns ns mJ mJ
C_{ies}			4.3	nF
Q_{Gon}			340	nC
R_{thJC}	(per IGBT)			0.3 K/W

Output Inverter D1 - D6

Symbol	Conditions	Maximum Ratings		
I_{F25}	$T_C = 25^\circ\text{C}$	140		A
I_{F80}	$T_C = 80^\circ\text{C}$	85		A

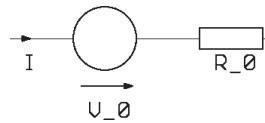
Symbol	Conditions	Characteristic Values		
		min.	typ.	max.
V_F	$I_F = 100\text{ A}$; $V_{GE} = 0\text{ V}$; $T_{VJ} = 25^\circ\text{C}$ $T_{VJ} = 125^\circ\text{C}$		1.9 1.4	2.2 V V
I_{RM} t_{rr}	$\left. \begin{array}{l} I_F = 60\text{ A}; di_F/dt = -500\text{ A}/\mu\text{s} \\ V_R = 300\text{ V}; V_{GE} = 0\text{ V} \end{array} \right\}$		28 100	A ns
R_{thJC}				0.61 K/W

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Equivalent Circuits for Simulation

Conduction



IGBT (typ. at $V_{GE} = 15\text{ V}$; $T_J = 125^\circ\text{C}$)
T1-T6

$$V_0 = 1.05\text{ V}; R_0 = 11.5\text{ m}\Omega$$

T7

$$V_0 = 1.05\text{ V}; R_0 = 21.5\text{ m}\Omega$$

Diode (typ. at $T_J = 125^\circ\text{C}$)

D1-D6

$$V_0 = 1.15\text{ V}; R_0 = 2.5\text{ m}\Omega$$

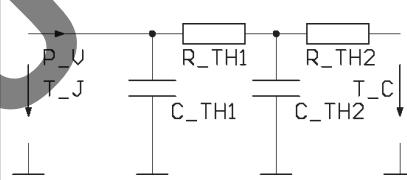
D7

$$V_0 = 1.15\text{ V}; R_0 = 12.5\text{ m}\Omega$$

D11-D16

$$V_0 = 0.85\text{ V}; R_0 = 4\text{ m}\Omega$$

Thermal Response



IGBT (typ.)

T1-T6

$$C_{th1} = 0.232\text{ J/K}; R_{th1} = 0.223\text{ K/W}$$

$$C_{th2} = 1.504\text{ J/K}; R_{th2} = 0.077\text{ K/W}$$

T7

$$C_{th1} = 0.123\text{ J/K}; R_{th1} = 0.419\text{ K/W}$$

$$C_{th2} = 0.944\text{ J/K}; R_{th2} = 0.131\text{ K/W}$$

Diode (typ.)

D1-D6

$$C_{th1} = 0.138\text{ J/K}; R_{th1} = 0.48\text{ K/W}$$

$$C_{th2} = 0.957\text{ J/K}; R_{th2} = 0.13\text{ K/W}$$

D7

$$C_{th1} = 0.038\text{ J/K}; R_{th1} = 1.74\text{ K/W}$$

$$C_{th2} = 0.435\text{ J/K}; R_{th2} = 0.36\text{ K/W}$$

D11-D16

$$C_{th1} = 0.112\text{ J/K}; R_{th1} = 0.568\text{ K/W}$$

$$C_{th2} = 0.745\text{ J/K}; R_{th2} = 0.162\text{ K/W}$$

Brake Chopper T7

Symbol	Conditions	Maximum Ratings		
V_{CES}	$T_{VJ} = 25^\circ\text{C}$ to 150°C	600		V
V_{GES}	Continuous	± 20		V
I_{C25}	$T_C = 25^\circ\text{C}$	75		A
I_{C80}	$T_C = 80^\circ\text{C}$	50		A
RBSOA	$V_{GE} = \pm 15 \text{ V}$; $R_G = 22 \Omega$; $T_{VJ} = 125^\circ\text{C}$ Clamped inductive load; $L = 100 \mu\text{H}$	$I_{CM} = 100$ $V_{CEK} \leq V_{CES}$		A
t_{sc} (SCSOA)	$V_{CE} = V_{CES}$; $V_{GE} = \pm 15 \text{ V}$; $R_G = 22 \Omega$; $T_{VJ} = 125^\circ\text{C}$ non-repetitive	10	μs	
P_{tot}	$T_C = 25^\circ\text{C}$	225		W

Symbol	Conditions	Characteristic Values		
		($T_{VJ} = 25^\circ\text{C}$, unless otherwise specified)	min.	typ.
$V_{CE(sat)}$	$I_C = 50 \text{ A}$; $V_{GE} = 15 \text{ V}$; $T_{VJ} = 25^\circ\text{C}$ $T_{VJ} = 125^\circ\text{C}$		1.9 2.1	2.3 V V
$V_{GE(th)}$	$I_C = 1 \text{ mA}$; $V_{GE} = V_{CE}$	4.5		6.5 V
I_{CES}	$V_{CE} = V_{CES}$; $V_{GE} = 0 \text{ V}$; $T_{VJ} = 25^\circ\text{C}$ $T_{VJ} = 125^\circ\text{C}$		0.5	0.5 mA mA
I_{GES}	$V_{CE} = 0 \text{ V}$; $V_{GE} = \pm 20 \text{ V}$		200	nA
$t_{d(on)}$ t_r $t_{d(off)}$ t_f E_{on} E_{off}	Inductive load, $T_{VJ} = 125^\circ\text{C}$ $V_{CE} = 300 \text{ V}$; $I_C = 50 \text{ A}$ $V_{GE} = \pm 15 \text{ V}$; $R_G = 22 \Omega$		50 55 300 30 2.3 1.7	ns ns ns ns mJ mJ
C_{ies}			2.8	nF
Q_{Gon}			120	nC
R_{thJC}			0.55	K/W

Brake Chopper D7

Symbol	Conditions	Maximum Ratings		
V_{RRM}	$T_{VJ} = 25^\circ\text{C}$ to 150°C	600		V
I_{F25}	$T_C = 25^\circ\text{C}$	35		A
I_{F80}	$T_C = 80^\circ\text{C}$	24		A
Symbol	Conditions	Characteristic Values		
V_F	$I_F = 50 \text{ A}$; $T_{VJ} = 25^\circ\text{C}$ $T_{VJ} = 125^\circ\text{C}$	min.	typ.	max.
			2.2 1.8	2.5 V V
I_R	$V_R = V_{RRM}$; $T_{VJ} = 25^\circ\text{C}$ $T_{VJ} = 125^\circ\text{C}$		0.1	0.1 mA mA
I_{RM} t_{rr}	$I_F = 15 \text{ A}$; $di_F/dt = -400 \text{ A}/\mu\text{s}$; $T_{VJ} = 125^\circ\text{C}$ $V_R = 300 \text{ V}$		13 90	A ns
R_{thJC}			2.1	K/W

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Temperature Sensor NTC

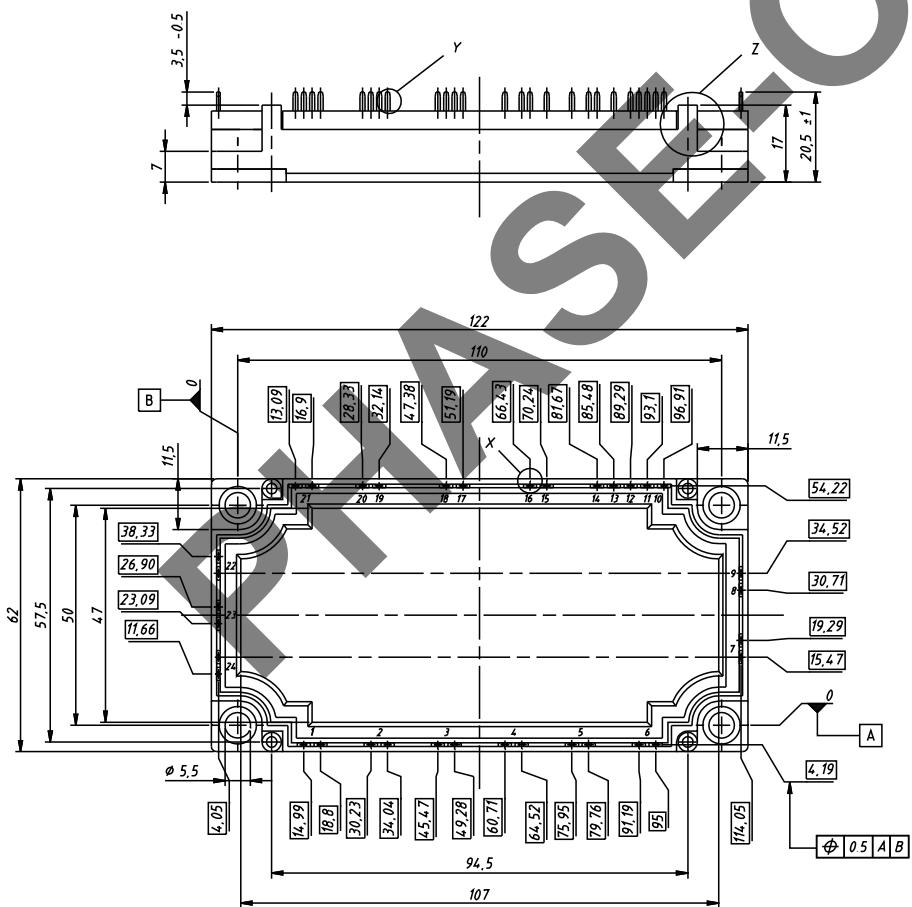
Symbol	Conditions	Characteristic Values		
		min.	typ.	max.
R_{25} $B_{25/50}$	$T = 25^\circ\text{C}$	4.75	5.0 3375	5.25 k Ω K

Module

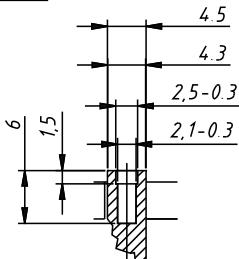
Symbol	Conditions	Maximum Ratings		
T_{VJ}	operating	-40...+125	°C	
T_{JM}		+150	°C	
T_{stg}		-40...+125	°C	
V_{ISOL}	$I_{ISOL} \leq 1 \text{ mA}; 50/60 \text{ Hz}$	2500	V~	
M_d	Mounting torque (M5)	3 - 6	Nm	

Symbol	Conditions	Characteristic Values		
		min.	typ.	max.
$R_{pin-chip}$		5		m Ω
d_s	Creepage distance on surface	6		mm
d_A	Strike distance in air	6		mm
R_{thCH}	with heatsink compound	0.01		K/W
Weight		300		g

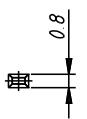
Dimensions in mm (1 mm = 0.0394")



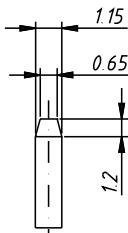
Detail Z



Detail X



Detail Y



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